

INCHANGE SEMICONDUCTOR

iscN-Channel MOSFET Transistor

TK14A65W, ITK14A65W

FEATURES

- Low drain-source on-resistance: RDs(ON) = 0.25Ω
- · Easy to control Gate switching
- Enhancement mode: Vth = 2.5 to 3.5V (VDs = 10 V, ID=0.69mA)
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

Rth(ch-c)

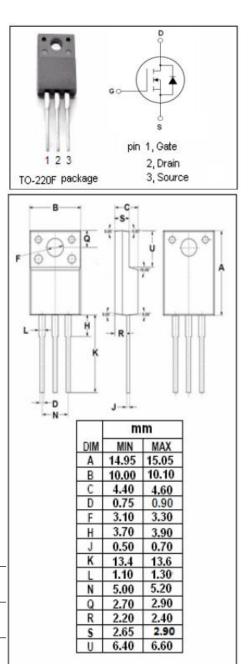
Rth(ch-a)

Switching Voltage Regulators

• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

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SYMBOL	PARAMETER	V	ALUE	UNIT				
V _{DSS}	Drain-Source Voltage		650	V				
V _{GS}	Gate-Source Voltage		±30	V				
ID	Drain Current-Continuous		13.7	А				
I _{DM}	Drain Current-Single Pulsed	54.8		A				
PD	Total Dissipation @Tc=25℃		40	W				
Tj	Max. Operating Junction Temperature	150		°C				
T _{stg}	Storage Temperature	-55~150		°C				
THERMAL CHARACTERISTICS								
SYMBOL	YMBOL PARAMETER		МАХ	UNIT				
Rth(ch-c)	Channel-to-case thermal resistance	3 13		°C/W				

Channel-to-ambient thermal resistance



°C/W

°C/W

3.13

62.5

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ELECTRICAL CHARACTERISTICS

 $T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 10mA	650			v
V _{GS} (th)	Gate Threshold Voltage	V _{DS} = 10V; I _D =0.69mA	2.5		3.5	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =6.9A			250	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±30V;V _{DS} =0V			±1	μA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 650V; V _{GS} = 0V			10	μA
V _{SDF}	Diode forward voltage	I _{DR} =13.7A, V _{GS} = 0 V			1.7	V

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